

The Electromagnetic Calorimeter of the CMS Experiment



8th Topical Seminar on Innovative Particle and Radiation Detectors - Siena 22/10/2002

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- General considerations and motivations
- Physics benchmark
- Crystals
- Photodetectors
- Readout
- Key points in energy resolution
- Regional Centers for assembly and test

LHC experimental conditions





CMS ECAL Structure



≈75000 PWO Crystals + Preshower (Endcaps)

Parameter	Barrel	Endcap
η coverage	η < 1.48	1.48 < η < 3.0
Granularity (Δη×Δφ)	0.0175×0.0175	varies in η
Crystal Dims. (cm ³)	2.18×2.18×23	2.85×2.85×22
Depth in X _e	25.8	24.7 (+3X _o)
No. of crystals	61,200	14,950
Crystal Volume (m ³)	8.14	3.04
Photodetector	APDs	VPTs
Modularity	36 supermodules	4 Dees



Motivations for Crystals

- Excellent energy resolution (over a wide range)
- High detection efficiency for low energy e and γ
- Structural compactness:
 - simple building blocks allowing easy mechanical assembly
 - hermetic coverage
 - fine transverse granularity
- Tower structure facilitates event reconstruction
 - straightforward cluster algorithms for energy and position
 - electron/photon identification



Instrumental Effects

Precision has a price... a long list to take care:

- Longitudinal and lateral shower containment
- Light production and collection
- Light collection uniformity
- Nuclear counter effect (leakage of particles in PD)
- Photo Detector gain (if any) stability
- Channel to channel intercalibration
- Electronic noise
- $\boldsymbol{\cdot}$ Dead material (energy loss and $\boldsymbol{\gamma}$ conversions)
- Temperature stability and uniformity
- Radiation damage
- Pileup



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A question of philosopy...

A crystal calorimeter is a very precise instrument that requires a tremendous effort to be finalized

- understand & optimize crystal parameters
- technology for growing crystals
- extreme resolution very fragile

Is it worth?

If you look for some specific reaction...



Higgs hunt: low mass?



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CMS ECAL benchmark

Low mass Higgs discovery:

$$\Gamma_{\rm H} (m_{\rm H} \cong 100 \text{ GeV}) \sim 2 - 100 \text{ MeV} ~ \Gamma_{\rm H} / m_{\rm H} \le 10^{-3}$$

Precision given by experimental resol

$$m_{\gamma\gamma} = 2 E_1 E_2 (1 - \cos\theta)$$

$$\frac{\sigma_{\rm m}}{\rm m} = \frac{1}{2} \left[\left(\frac{\sigma_1}{\rm E_1} \right)^2 + \left(\frac{\sigma_2}{\rm E_2} \right)^2 + \left(\frac{\sigma_{\theta}}{\rm tg\theta/2} \right)^2 \right]^{1/2}$$

T

$$\frac{\sigma(E)}{E} = \frac{a}{\sqrt{E}} \oplus \frac{b}{E} \oplus c$$

$$\begin{array}{l} a \sim 0.025 \; \text{GeV}^{\mbox{\tiny 1/2}} \\ \text{arget} \rightarrow & b < 200 \; \text{MeV} \\ c \sim 0.005 \\ \text{and an angular resolution} \\ \sigma_{\theta} \sim 50 \; \text{mrad}/\sqrt{E} \end{array}$$



L3 photon measurements

Beautiful instrument & excellent physics results





Which crystal?

	Nal(TI)	BaF2	CsI(TI)	Csl	CeF3	BGO	PWO	
ρ	3.67	4.88	4.53	4.53	6.16	7.13	8.26	g/cm ³
X0	2.59	2.05	1.85	1.85	1.68	1.12	0.89	ст
RM	4.5	3.4	3.8	3.8	2.6	2.4	2.2	cm
τ	250	0.8/620	1000	20	30	300	15	ns
λ <mark>p</mark>	410	220/310	565	310	310/340	480	420	nm
n (λp)	1.85	1.56	1.80	1.80	1.68	2.15	2.29	
LY	100%	15%	85%	7%	5%	10%	0.2%	%Nal

Typical light yield of NaI ~ 40000 γ /MeV



The choice of Lead Tungstate

Parameter		Value
Radiation length	cm	0.89
Moliere radius	cm	2.2
Hardness	Moh	4
Refractive index		2.3
Peak emission	nm	440
% of light in 25 ns		80%
Light yield (23 cm)	γ/MeV	100



- Fast scintillation
- Small X₀ and R_m
- Intrinsic radiation hardness
- Relatively easy to grow
- Massive production capability

- Low Light Yield
- High index of refraction
- Strong LY dependance on T



Main CMS ECAL challenges

- Improve the low level of light yield of crystals
- Keep fast response (understand decay kinetics)
- Insure radiation resistance
- Improve growing and production techniques
- Achieve longitudinal response uniformity
- Develop solid state photodtector with gain (APD)
- Develop suitable radiation hard electronics
- Control effects below few permill
- Design low-Z support structure
- Test and assembly ~ 75000 crystals



Crystals R&D 1995 - 1998



Facts on Radiation Damage





Major R&D problem

- \rightarrow Only e.m. radiation produces a damage
- \rightarrow Scintillation mechanism is not affected
- \rightarrow Only crystal transparency is reduced

creation of color centers

 \rightarrow Damage level depends on dose rate

creation and annealing of color centers at room temperature

- \rightarrow Damage level reaches an equilibrium after a small administered dose
- \rightarrow Partial damage recovery in few hours
- \rightarrow Loss in extracted light of few % is tolerable and can be followed with a monitor system

Dose rates [Gy/h] in ECAL at luminosity $L=10^{34}$ cm⁻²s⁻¹ Siena 22/10/2002





Crystals Preproduction

Sept. 1998 to Dec. 2000

6000 crystals produced by BTCP





Preproduction Goals





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Preproduction Goals





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2001: Crystals New Technology

Technology steps in Bogoroditsk



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Production of barrel crystals started in 2001: 5700 crystals delivered In parallel R&D to increase productivity (driven by endcap ingot success)

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New Technology: Quality



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New Technology: Production

138 ovens upgraded for up to 85mm



New cutting technology: yield!







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Crystals New Technology

Technology for 65mm ingots under control: quality comparable with "standard crystals"



Further increase of the PWO ingot diameter under study: 2Endcap or 4Barrel crystals in one ingot is feasible

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Crystal production schedule

Years	2001			2002			2003				2004				2005			
Quarters	1Q	2Q	3Q	4Q	1Q	2Q	3Q	4Q	1Q	2Q	3Q	4Q	1Q	2Q	3Q	4Q	1Q	2Q
CERN/ISTC #354b- 6000 barrel																		
Delivered	6000																	
CERN/ISTC #1718- 30000 barrel																		
Schedule Sept 2001		1500	1200	2100	2500	2600	1800	2600	2900	2900	2900	2900	2900	1200				
New.sched	15	00	500	500	200	200	200	400	2500	4000	4000	4000	4000	4000	3200	800		
Delivered	15	00	500	500	200	200	200											
CERN/ETH	Z Con	tract 26	õ00 b:	arrel														
Contract SCIONIX							2600	2600	2600	2600	2600	2600	2600	2600	2600	2600		
Delivered							2600											
Additionna	l order	for Ba	rrel (37	th SM -	⊦ spare	s)											-	
Potential product.																2150		
Dotortial EE	tais pro				<u> </u>	<u> </u>			Ï			<u> </u>	İ					
production										200	400	400	400	400	1200	1450	7000	3550
Barrel Total Cumulative	7500		8000	8500	8700	8900	11.7 K	14.7 K	19.8 K	26.4 K	33.0 K	39.6 K	46.2 K	52.8 K	58.6 K	64.15 K		
EE Total Cumulative										200	600	1000	1400	1800	3000	4450	11.45 K	15.0K

Assumes 2 crystals per ingot for barrel and endcap



Avalanche Photo Diodes - Barrel





- Insensitive to B-field (4T)
- Internal gain (needed for PWO, M=50 used, V_{M50}≈380V)
- Good match to PWO scintillation spectrum (Q.E.~80%)



Avalanche Photo Diodes - Barrel

Critical points

- \bullet Contributions to all $\sigma({\rm E})/\!\!/\!{\rm E}$ terms
 - C & Idark \Rightarrow b (1/E)
 - excess noise factor \Rightarrow a (1/ \sqrt{E})
 - Gain stability \Rightarrow c
- Nuclear counter effect
- Radiation hardness



APDs optimized with an extensive R&D program are now in production

Capacitance 75 pF & Idark few nA $\Rightarrow b = 150 \text{ MeV} (\Sigma 5x5 \tau_s = 40 \text{ns})$ F=2.2 (\rightarrow fluctuations in multiplication) $\Rightarrow a \text{ increase } 1.6\% \rightarrow 2.3\%$ dM/dV = 3%/V and dM/dT = -2.3%/°C $\Rightarrow c \sim 0.5\%$ develop very stable systems

 $d_{eff} \cong 6 \ \mu m$ (\rightarrow acceptable response to ionizing radiation)

Idark increases with neutron irradiation: $\sqrt{2}$ contribution to noise of single channel after 10 years running

ok



Vacuum Phototriodes - Endcaps





• Q.E. ~ 20% at 420 nm





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Read out chain/old



- 40 MHz clock
- High dynamic range to measure an energy interval 50MeV →2TeV

ALL RADIATION HARD

Energy

 \rightarrow Light

PbWO₄

Crystal

A difficult and costly project!





Read out chain/new

- Major revision of the project imposed by budget and possible thanks to 0.25µm CMOS rad hard technology: $\succ \Sigma$ trigger e data storage on detector > read out of data only if L1 OK Same scheme \succ three links each trigger tower (25 xl) of TP (1994) xtais Front End APD Readout (2) Timing (-Si avalanche (iii) → Readout photodiode To Mother Powo, costal Board Dicital (Fenix) readout ○→ Insper Light Current Voltage Bit Energy Light Current Voltage Bits Floating point Preamplifier ADC Very Front End Board (5 Channels/VFE board) Front End Board (25 Channels/FE board)
 - Reduction of about a factor 8 in the number of data links
 - •Simplification of off-detector electronics
 - •Equivalent performances



New construction scheme

Bare/Dressed Super Modules





Design Resolution is achievable



280 GeV electrons:

 no sign of rear leakage, which could cause direct signal in APD

Resolution as a function of energy:

 on 1999 prototype, matrix with 30 preproduction crystals and APDs

$$\frac{\sigma}{E} = \frac{2.74\%}{\sqrt{E}} \oplus 0.40\% \oplus \frac{142 \text{MeV}}{E}$$



Energy resolution

Standard parametrization:



- a: stochastic term from Poisson-like fluctuations
 - sampling contribution
 - (natural advantage of omogeneous calorimeters)
 - intrinsic contribution from photostatistics (\Rightarrow L.Y.)
 - other contributions often important
- b: noise contribution, relevant at low energy
 - electronic noise converted in energy units through N $_{\rm pe}/{\rm MeV}~\Rightarrow$ b depends on Light Yield too
- c: constant contribution, dominated by stability
 - dangerous limitation to high energy resolution
 - important contribution from calibration constants



Resolution: stocastic term a

- photostatistics contribution, including
 - LY
 - light collection efficiency
 - geometrical efficiency of the photodetector
 - photocatode quantum efficiency
 - $N_{pe}/GeV = 4000 \text{ for } 0.5 \text{ cm}^2 \text{ APD } \rightarrow 1.6\%$
- electron current multiplication in APD, contributing a square root of excess noise factor, F = 2
 - 1.6×1.4 = 2.25%
- Lateral containment (5×5 matrix) \rightarrow 1.5% Total stochastic term a = 2.7 %



Resolution: noise term b

40 ns shaping time, summed over 5x5 channels

- Serial noise (p.d. capacitance) $\propto 1/\sqrt{t}$
 - 150 MeV
- Parallel noise (dark current) $\propto \sqrt{t}$, mostly radiation induced
 - negligible at the start of the experiment
 - 30 MeV after one year at low luminosity
 - 100 MeV after one year at high luminosity
- Physics pile-up (simulated, with big uncertainties)
 - low luminosity 30 MeV
 - high luminosity 100 MeV
- Total contribution
 - low luminosity 155 MeV
 - high luminosity 210 MeV



Resolution: constant term c

Most dangerous at high energy

- leakage (front, rear, dead material)
 CMS full shower simulation < 0.2 %
- system instabilities designed to be at the permill level $t \sim 3t_{cal}$
 - temperature stabilization < 0.1 °C (dLY/dT = -2.0%/°C @ 18°C ; dM/dT ~ -2.3 %/°C)
 - APD bias stable at ±20 mV (dM/dV = 3%/V)

Key issues to keep $c \sim 0.5$ % :

·light collection uniformity

 \cdot intercalibration by monitor and physics signals at 0.5 % including the radiation damage effect



Uniformity of light collection

- Focusing effect due to tapered shape of crystals (first seen and studied in L3)
- •High index of refraction (n=2.3) enhance the effect: $\theta_c \approx 26^\circ$

Uniformity can be controlled by depolishing one lateral face with a given roughness

PAY A LOSS IN LY





Effect of non uniformity

• A non uniformity of the light collection in the shower max region may significantly contribute to the constant term in the energy resolution







Electron vs Light signal





Monitor: L3 10 years of follow-up

Response may change! Even if not foreseen



- system able to track the BGO response decrease (few %/year)
- porting of previous year calibration: 1.3%
- spread after Xe+Bhabha corrections: 0.8% from calibration in 1991



In 1999 0.5% from calibration after refinements of methods



Calibration on test beam

Why pre-calibration of each single channel is desirable?

• Full system test

• Be ready as soon as possible for precision measurement independently from other CMS sub-detectors (precision on intercalibration has a direct impact on the constant term of the energy resolution)

A partial calibration is anyway mandatory to understand

- Geometrical effects (energy deposition depends on η)
- Effects of gaps between crystals, modules
- Thermal stability
- Gain stability in electronics chain
- Monitoring system
- MC simulation in all its aspects
- In situ calibration through reference regions



Compare Intercalibration







ECAL Regional Centers





Crystal quality insurance





Automatic control of:

- Dimensions
- Transmission (radiation hardness)
- Light yield and uniformity



Module assembly and test



Transport of modules to CERN





Conclusions

- A challanging project
- Intense and rewording R&D effort performed
- Now in the construction phase
- Few years of construction (\rightarrow 2005)
- Few years to understand in detail the system behaviour
- Aiming to outstanding physics results







